



Welcome to [E-XFL.COM](#)

### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	400MHz
Co-Processors/DSP	Communications; QUICC Engine
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	668-BBGA Exposed Pad
Supplier Device Package	668-PBGA-PGE (29x29)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8358vragdda">https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8358vragdda</a>

- ATM (AAL2/AAL5) to Ethernet (IP) interworking in accordance with RFC2684 including bridging of ATM ports to Ethernet ports
- Extensive support for ATM statistics and Ethernet RMON/MIB statistics
- AAL2 protocol rate up to 4 CPS at OC-3/STM-1 rate
- Packet over Sonet (POS) up to 622-Mbps full-duplex 124 MultiPHY
- POS hardware; microcode must be loaded as an IIRAM package
- Transparent up to 70-Mbps full-duplex
- HDLC up to 70-Mbps full-duplex
- HDLC BUS up to 10 Mbps
- Asynchronous HDLC
- UART
- BISYNC up to 2 Mbps
- User-programmable Virtual FIFO size
- QUICC multichannel controller (QMC) for 64 TDM channels
- One UTOPIA/POS interface on the MPC8358E supporting 31/124 MultiPHY
- Two serial peripheral interfaces (SPI); SPI2 is dedicated to Ethernet PHY management
- Four TDM interfaces on the MPC8358E with 1-bit mode for E3/T3 rates in clear channel
- Sixteen independent baud rate generators and 30 input clock pins for supplying clocks to UCC serial channels
- Four independent 16-bit timers that can be interconnected as four 32-bit timers
- Interworking functionality:
  - Layer 2 10/100-Base T Ethernet switch
  - ATM-to-ATM switching (AAL0, 2, 5)
  - Ethernet-to-ATM switching with L3/L4 support
  - PPP interworking
- Security engine is optimized to handle all the algorithms associated with IPSec, SSL/TLS, SRTP, 802.11i®, iSCSI, and IKE processing. The security engine contains four crypto-channels, a controller, and a set of crypto execution units (EUs).
  - Public key execution unit (PKEU) supporting the following:
    - RSA and Diffie-Hellman
    - Programmable field size up to 2048 bits
    - Elliptic curve cryptography
    - F2m and F(p) modes
    - Programmable field size up to 511 bits
  - Data encryption standard execution unit (DEU)
    - DES, 3DES
    - Two key (K1, K2) or three key (K1, K2, K3)
    - ECB and CBC modes for both DES and 3DES

- Multiple master support
- Master or slave I<sup>2</sup>C mode support
- On-chip digital filtering rejects spikes on the bus
- System initialization data is optionally loaded from I<sup>2</sup>C-1 EPROM by boot sequencer embedded hardware
- DMA controller
  - Four independent virtual channels
  - Concurrent execution across multiple channels with programmable bandwidth control
  - All channels accessible by local core and remote PCI masters
  - Misaligned transfer capability
  - Data chaining and direct mode
  - Interrupt on completed segment and chain
  - DMA external handshake signals:  $\overline{\text{DMA\_DREQ}}[0:3]/\overline{\text{DMA\_DACK}}[0:3]/\overline{\text{DMA\_DONE}}[0:3]$ . There is one set for each DMA channel. The pins are multiplexed to the parallel IO pins with other QE functions.
- DUART
  - Two 4-wire interfaces (RxD, TxD, RTS, CTS)
  - Programming model compatible with the original 16450 UART and the PC16550D
- System timers
  - Periodic interrupt timer
  - Real-time clock
  - Software watchdog timer
  - Eight general-purpose timers
- IEEE Std. 1149.1™-compliant, JTAG boundary scan
- Integrated PCI bus and SDRAM clock generation

## 2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8358E. The device is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

Table 5 shows the estimated typical I/O power dissipation for the device.

**Table 5. Estimated Typical I/O Power Dissipation**

Interface	Parameter	GV <sub>DD</sub> (1.8 V)	GV <sub>DD</sub> (2.5 V)	OV <sub>DD</sub> (3.3 V)	LV <sub>DD</sub> (3.3 V)	LV <sub>DD</sub> (2.5 V)	Unit	Comments
DDR I/O 65% utilization 2.5 V R <sub>s</sub> = 20 Ω R <sub>t</sub> = 50 Ω 2 pairs of clocks	200 MHz, 1x32 bits	0.3	0.46	—	—	—	W	—
	200 MHz, 1x64 bits	0.4	0.58	—	—	—	W	—
	200 MHz, 2x32 bits	0.6	0.92	—	—	—	W	—
	266 MHz, 1x32 bits	0.35	0.56	—	—	—	W	—
	266 MHz, 1x64 bits	0.46	0.7	—	—	—	W	—
	266 MHz, 2x32 bits	0.7	1.11	—	—	—	W	—
Local Bus I/O Load = 25 pF 3 pairs of clocks	133 MHz, 32 bits	—	—	0.22	—	—	W	—
	83 MHz, 32 bits	—	—	0.14	—	—	W	—
	66 MHz, 32 bits	—	—	0.12	—	—	W	—
	50 MHz, 32 bits	—	—	0.09	—	—	W	—
PCI I/O Load = 30 pF	33 MHz, 32 bits	—	—	0.05	—	—	W	—
	66 MHz, 32 bits	—	—	0.07	—	—	W	—
10/100/1000 Ethernet I/O Load = 20 pF	MII or RMII	—	—	—	0.01	—	W	Multiply by number of interfaces used.
	GMII or TBI	—	—	—	0.04	—	W	
	RGMII or RTBI	—	—	—	—	0.04	W	
Other I/O	—	—	—	0.1	—	—	W	—

## 4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8358E.

### NOTE

The rise/fall time on QUICC Engine block input pins should not exceed 5 ns. This should be enforced especially on clock signals. Rise time refers to signal transitions from 10% to 90% of V<sub>DD</sub>; fall time refers to transitions from 90% to 10% of V<sub>DD</sub>.

**Table 12. QUICC Engine Block Operating Frequency Limitations (continued)**

Interface	Interface Operating Frequency (MHz)	Max Interface Bit Rate (Mbps)	Min QUICC Engine Operating Frequency <sup>1</sup> (MHz)	Notes
UART/async HDLC	3.68 (max internal ref clock)	115 (Kbps)	20	—
BISYNC	2 (max)	2	20	—
USB	48 (ref clock)	12	96	—

**Notes:**

1. The QUICC Engine module needs to run at a frequency higher than or equal to what is listed in this table.
2. 'F' is the actual interface operating frequency.
3. The bit rate limit is independent of the data bus width (that is, the same for serial, nibble, or octal interfaces).
4. TDM in high-speed mode for serial data interface.

## 6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR and DDR2 SDRAM interface of the MPC8358E.

### 6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 13 provides the recommended operating conditions for the DDR2 SDRAM component(s) of the device when  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$ .

**Table 13. DDR2 SDRAM DC Electrical Characteristics for  $GV_{DD}(\text{typ}) = 1.8 \text{ V}$** 

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	$GV_{DD}$	1.71	1.89	V	1
I/O reference voltage	$MV_{REF}$	$0.49 \times GV_{DD}$	$0.51 \times GV_{DD}$	V	2
I/O termination voltage	$V_{TT}$	$MV_{REF} - 0.04$	$MV_{REF} + 0.04$	V	3
Input high voltage	$V_{IH}$	$MV_{REF} + 0.125$	$GV_{DD} + 0.3$	V	—
Input low voltage	$V_{IL}$	-0.3	$MV_{REF} - 0.125$	V	—
Output leakage current	$I_{OZ}$	—	$\pm 10$	$\mu\text{A}$	4
Output high current ( $V_{OUT} = 1.420 \text{ V}$ )	$I_{OH}$	-13.4	—	mA	—
Output low current ( $V_{OUT} = 0.280 \text{ V}$ )	$I_{OL}$	13.4	—	mA	—
$MV_{REF}$ input leakage current	$I_{VREF}$	—	$\pm 10$	$\mu\text{A}$	—

Table 16 provides the DDR capacitance when  $GV_{DD}(typ) = 2.5\text{ V}$ .

**Table 16. DDR SDRAM Capacitance for  $GV_{DD}(typ) = 2.5\text{ V}$**

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input/output capacitance: DQ, DQS	$C_{IO}$	6	8	pF	1
Delta input/output capacitance: DQ, DQS	$C_{DIO}$	—	0.5	pF	1

**Note:**

1. This parameter is sampled.  $GV_{DD} = 2.5\text{ V} \pm 0.125\text{ V}$ ,  $f = 1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

## 6.2 DDR and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR and DDR2 SDRAM interface.

### 6.2.1 DDR and DDR2 SDRAM Input AC Timing Specifications

Table 17 provides the input AC timing specifications for the DDR2 SDRAM interface when  $GV_{DD}(typ) = 1.8\text{ V}$ .

**Table 17. DDR2 SDRAM Input AC Timing Specifications for  $GV_{DD}(typ) = 1.8\text{ V}$**

At recommended operating conditions with  $GV_{DD}$  of  $1.8\text{ V} \pm 5\%$ .

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	$V_{IL}$	—	$MV_{REF} - 0.25$	V	—
AC input high voltage	$V_{IH}$	$MV_{REF} + 0.25$	—	V	—

Table 18 provides the input AC timing specifications for the DDR SDRAM interface when  $GV_{DD}(typ) = 2.5\text{ V}$ .

**Table 18. DDR SDRAM Input AC Timing Specifications**

At recommended operating conditions with  $GV_{DD}$  of  $2.5\text{ V} \pm 5\%$ .

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	$V_{IL}$	—	$MV_{REF} - 0.31$	V	—
AC input high voltage	$V_{IH}$	$MV_{REF} + 0.31$	—	V	—

**Note:**

1. Maximum possible skew between a data strobe ( $MDQS[n]$ ) and any corresponding bit of data ( $MDQ[8n + \{0...7\}]$  if  $0 \leq n \leq 7$ ) or ECC ( $MECC[\{0...7\}]$  if  $n = 8$ ).

## 8.1 Three-Speed Ethernet Controller (10/100/1000 Mbps)—GMII/MII/RMII/TBI/RGMII/RTBI Electrical Characteristics

The electrical characteristics specified here apply to all GMII (gigabit media independent interface), MII (media independent interface), RMII (reduced media independent interface), TBI (ten-bit interface), RGMII (reduced gigabit media independent interface), and RTBI (reduced ten-bit interface) signals except MDIO (management data input/output) and MDC (management data clock). The MII, RMII, GMII, and TBI interfaces are only defined for 3.3 V, while the RGMII and RTBI interfaces are only defined for 2.5 V. The RGMII and RTBI interfaces follow the Hewlett-Packard reduced pin-count interface for Gigabit Ethernet Physical Layer Device Specification Version 1.2a (9/22/2000). The electrical characteristics for the MDIO and MDC are specified in [Section 8.3, “Ethernet Management Interface Electrical Characteristics.”](#)

### 8.1.1 10/100/1000 Ethernet DC Electrical Characteristics

The electrical characteristics specified here apply to media independent interface (MII), reduced gigabit media independent interface (RGMII), reduced ten-bit interface (RTBI), reduced media independent interface (RMII) signals, management data input/output (MDIO) and management data clock (MDC).

The MII and RMII interfaces are defined for 3.3 V, while the RGMII and RTBI interfaces can be operated at 2.5 V. The RGMII and RTBI interfaces follow the *Reduced Gigabit Media-Independent Interface (RGMII) Specification Version 1.3*. The RMII interface follows the *RMII Consortium RMII Specification Version 1.2*.

**Table 24. RGMII/RTBI, GMII, TBI, MII, and RMII DC Electrical Characteristics (when operating at 3.3 V)**

Parameter	Symbol	Conditions		Min	Max	Unit	Notes
Supply voltage 3.3 V	$V_{DD}$	—		2.97	3.63	V	1
Output high voltage	$V_{OH}$	$I_{OH} = -4.0 \text{ mA}$	$V_{DD} = \text{Min}$	2.40	$V_{DD} + 0.3$	V	—
Output low voltage	$V_{OL}$	$I_{OL} = 4.0 \text{ mA}$	$V_{DD} = \text{Min}$	GND	0.50	V	—
Input high voltage	$V_{IH}$	—	—	2.0	$V_{DD} + 0.3$	V	—
Input low voltage	$V_{IL}$	—	—	-0.3	0.90	V	—
Input current	$I_{IN}$	$0 \text{ V} \leq V_{IN} \leq V_{DD}$		—	$\pm 10$	$\mu\text{A}$	—

**Note:**

1. GMII/MII pins that are not needed for RGMII, RMII, or RTBI operation are powered by the  $OV_{DD}$  supply.

**Table 37. IEEE 1588 Timer AC Specifications (continued)**

Parameter	Symbol	Min	Max	Unit	Notes
Timer alarm to output valid	$t_{TMRAL}$	—	—	—	2

**Notes:**

1. The timer can operate on rtc\_clock or tmr\_clock. These clocks get muxed and any one of them can be selected. The minimum and maximum requirement for both rtc\_clock and tmr\_clock are the same.
2. These are asynchronous signals.
3. Inputs need to be stable at least one TMR clock.

## 9 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface of the MPC8358E.

### 9.1 Local Bus DC Electrical Characteristics

Table 38 provides the DC electrical characteristics for the local bus interface.

**Table 38. Local Bus DC Electrical Characteristics**

Parameter	Symbol	Min	Max	Unit
High-level input voltage	$V_{IH}$	2	$OV_{DD} + 0.3$	V
Low-level input voltage	$V_{IL}$	−0.3	0.8	V
High-level output voltage, $I_{OH} = -100 \mu A$	$V_{OH}$	$OV_{DD} - 0.4$	—	V
Low-level output voltage, $I_{OL} = 100 \mu A$	$V_{OL}$	—	0.2	V
Input current	$I_{IN}$	—	$\pm 10$	$\mu A$

### 9.2 Local Bus AC Electrical Specifications

Table 39 describes the general timing parameters of the local bus interface of the device.

**Table 39. Local Bus General Timing Parameters—DLL Enabled**

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Local bus cycle time	$t_{LBK}$	7.5	—	ns	2
Input setup to local bus clock (except LUPWAIT)	$t_{LBIVKH1}$	1.7	—	ns	3, 4
LUPWAIT input setup to local bus clock	$t_{LBIVKH2}$	1.9	—	ns	3, 4
Input hold from local bus clock (except LUPWAIT)	$t_{LBIXKH1}$	1.0	—	ns	3, 4
LUPWAIT input hold from local bus clock	$t_{LBIXKH2}$	1.0	—	ns	3, 4
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT1}$	1.5	—	ns	5
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT2}$	3.0	—	ns	6
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT3}$	2.5	—	ns	7



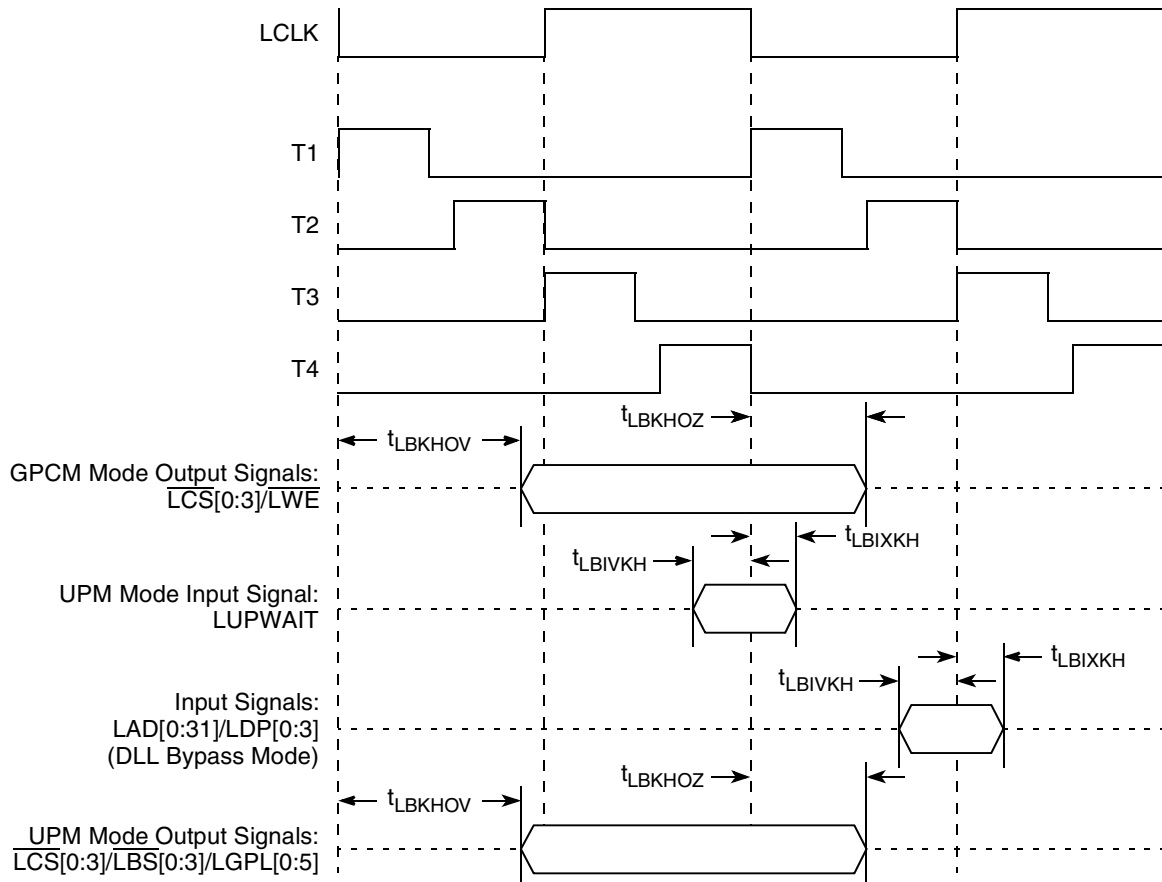


Figure 26. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4 (DLL Bypass Mode)

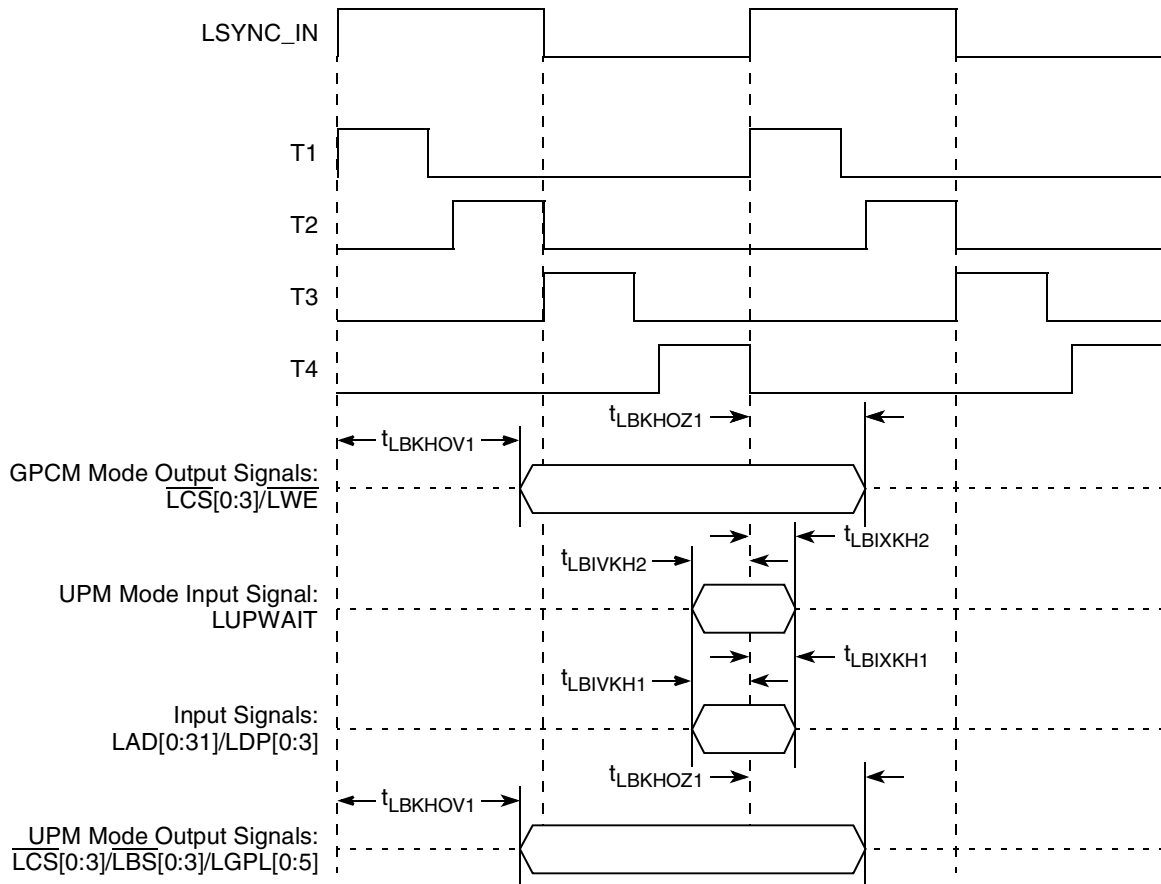


Figure 27. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4 (DLL Enabled)

## 10 JTAG

This section describes the DC and AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the MPC8358E.

### 10.1 JTAG DC Electrical Characteristics

Table 41 provides the DC electrical characteristics for the IEEE 1149.1 (JTAG) interface of the device.

Table 41. JTAG interface DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	$V_{OH}$	$I_{OH} = -6.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 6.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V
Input high voltage	$V_{IH}$	—	2.5	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	$0 \text{ V} \leq V_{IN} \leq OV_{DD}$	—	$\pm 10$	$\mu\text{A}$

**Table 47. PCI AC Timing Specifications at 33 MHz**

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Clock to output valid	$t_{PCKHOV}$	—	11	ns	2
Output hold from clock	$t_{PCKHOX}$	2	—	ns	2
Clock to output high impedance	$t_{PCKHOZ}$	—	14	ns	2, 3
Input setup to clock	$t_{PCIVKH}$	7.0	—	ns	2, 4
Input hold from clock	$t_{PCIXKH}$	0.3	—	ns	2, 4

**Notes:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
2. See the timing measurement conditions in the *PCI 2.2 Local Bus Specifications*.
3. For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
4. Input timings are measured at the pin.

Figure 35 provides the AC test load for PCI.

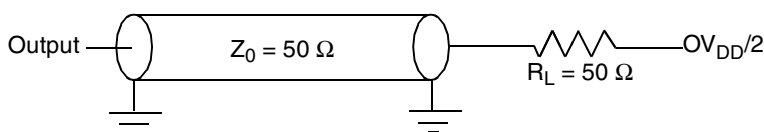

**Figure 35. PCI AC Test Load**

Figure 36 shows the PCI input AC timing conditions.

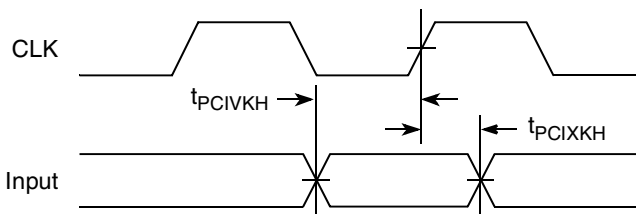

**Figure 36. PCI Input AC Timing Measurement Conditions**

Figure 37 shows the PCI output AC timing conditions.

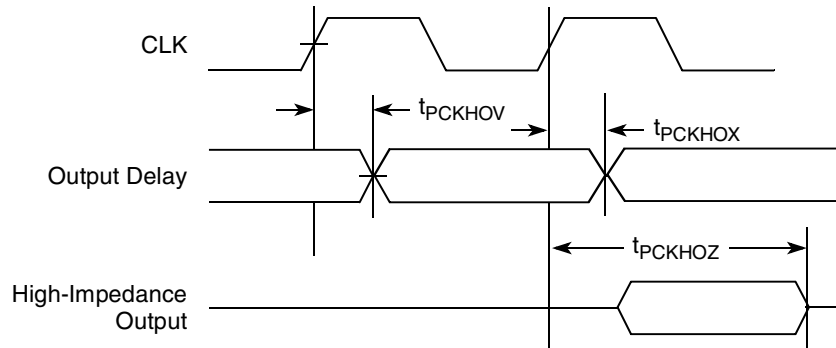


Figure 37. PCI Output AC Timing Measurement Condition

## 13 Timers

This section describes the DC and AC electrical specifications for the timers of the MPC8358E.

### 13.1 Timers DC Electrical Characteristics

Table 48 provides the DC electrical characteristics for the device timer pins, including  $TIN$ ,  $\overline{TOUT}$ ,  $\overline{TGATE}$ , and  $RTC\_CLK$ .

Table 48. Timers DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	$V_{OH}$	$I_{OH} = -6.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 6.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	$0 \text{ V} \leq V_{IN} \leq OV_{DD}$	—	$\pm 10$	$\mu\text{A}$

### 13.2 Timers AC Timing Specifications

Table 49 provides the timer input and output AC timing specifications.

Table 49. Timers Input AC Timing Specifications<sup>1</sup>

Characteristic	Symbol <sup>2</sup>	Typ	Unit
Timers inputs—minimum pulse width	$t_{TIWID}$	20	ns

**Notes:**

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of  $CLKIN$ . Timings are measured at the pin.
2. Timers inputs and outputs are asynchronous to any visible clock. Timers outputs should be synchronized before use by any external synchronous logic. Timers inputs are required to be valid for at least  $t_{TIWID}$  ns to ensure proper operation.

Figure 39 provides the AC test load for the GPIO.

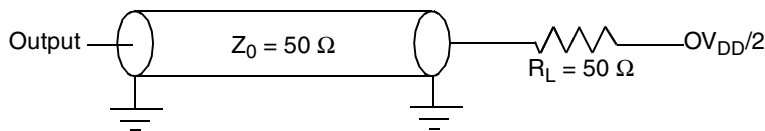


Figure 39. GPIO AC Test Load

## 15 IPIC

This section describes the DC and AC electrical specifications for the external interrupt pins of the MPC8358E.

### 15.1 IPIC DC Electrical Characteristics

Table 52 provides the DC electrical characteristics for the external interrupt pins of the IPIC.

Table 52. IPIC DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Input high voltage	$V_{IH}$	—	2.0	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	—	—	$\pm 10$	$\mu A$
Output low voltage	$V_{OL}$	$I_{OL} = 6.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V

**Notes:**

1. This table applies for pins  $\overline{IRQ}[0:7]$ ,  $\overline{IRQ\_OUT}$ ,  $\overline{MCP\_OUT}$ , and CE ports Interrupts.
2.  $\overline{IRQ\_OUT}$  and  $\overline{MCP\_OUT}$  are open drain pins, thus  $V_{OH}$  is not relevant for those pins.

### 15.2 IPIC AC Timing Specifications

Table 53 provides the IPIC input and output AC timing specifications.

Table 53. IPIC Input AC Timing Specifications<sup>1</sup>

Characteristic	Symbol <sup>2</sup>	Min	Unit
IPIC inputs—minimum pulse width	$t_{PIWID}$	20	ns

**Notes:**

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. IPIC inputs and outputs are asynchronous to any visible clock. IPIC outputs should be synchronized before use by any external synchronous logic. IPIC inputs are required to be valid for at least  $t_{PIWID}$  ns to ensure proper operation when working in edge triggered mode.

## 16 SPI

This section describes the DC and AC electrical specifications for the SPI of the MPC8358E.

**Table 59. UTOPIA AC Timing Specifications<sup>1</sup> (continued)**

Characteristic	Symbol <sup>2</sup>	Min	Max	Unit	Notes
UTOPIA inputs—External clock input setup time	$t_{UEIVKH}$	4.2	—	ns	—
UTOPIA inputs—Internal clock input hold time	$t_{UIIXKH}$	2.4	—	ns	—
UTOPIA inputs—External clock input hold time	$t_{UEIXKH}$	1	—	ns	—

**Notes:**

- Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
- The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{UIKH\text{OX}}$  symbolizes the UTOPIA outputs internal timing (UI) for the time  $t_{\text{UTOPIA}}$  memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).

Figure 45 provides the AC test load for the UTOPIA.

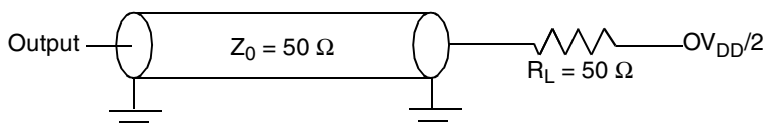
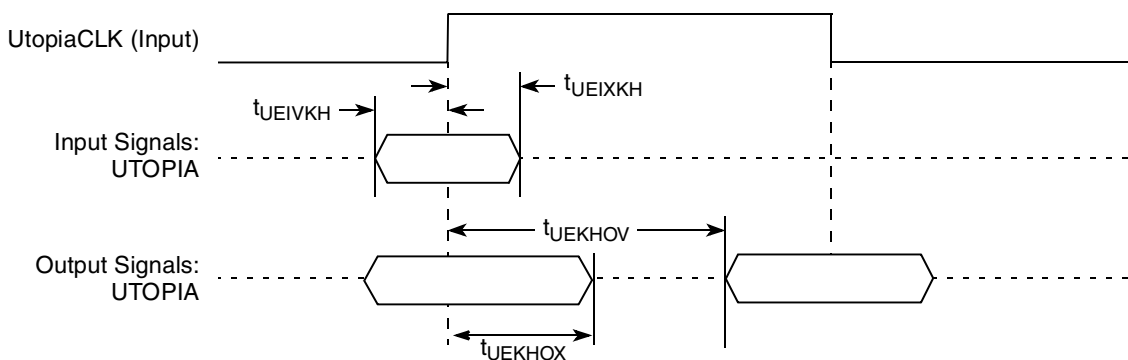

**Figure 45. UTOPIA AC Test Load**

Figure 46 and Figure 47 represent the AC timing from Table 55. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 46 shows the UTOPIA timing with external clock.


**Figure 46. UTOPIA AC Timing (External Clock) Diagram**

## 21.2 Mechanical Dimensions of the PBGA Package

Figure 52 depicts the mechanical dimensions and bottom surface nomenclature of the 668-PBGA package.

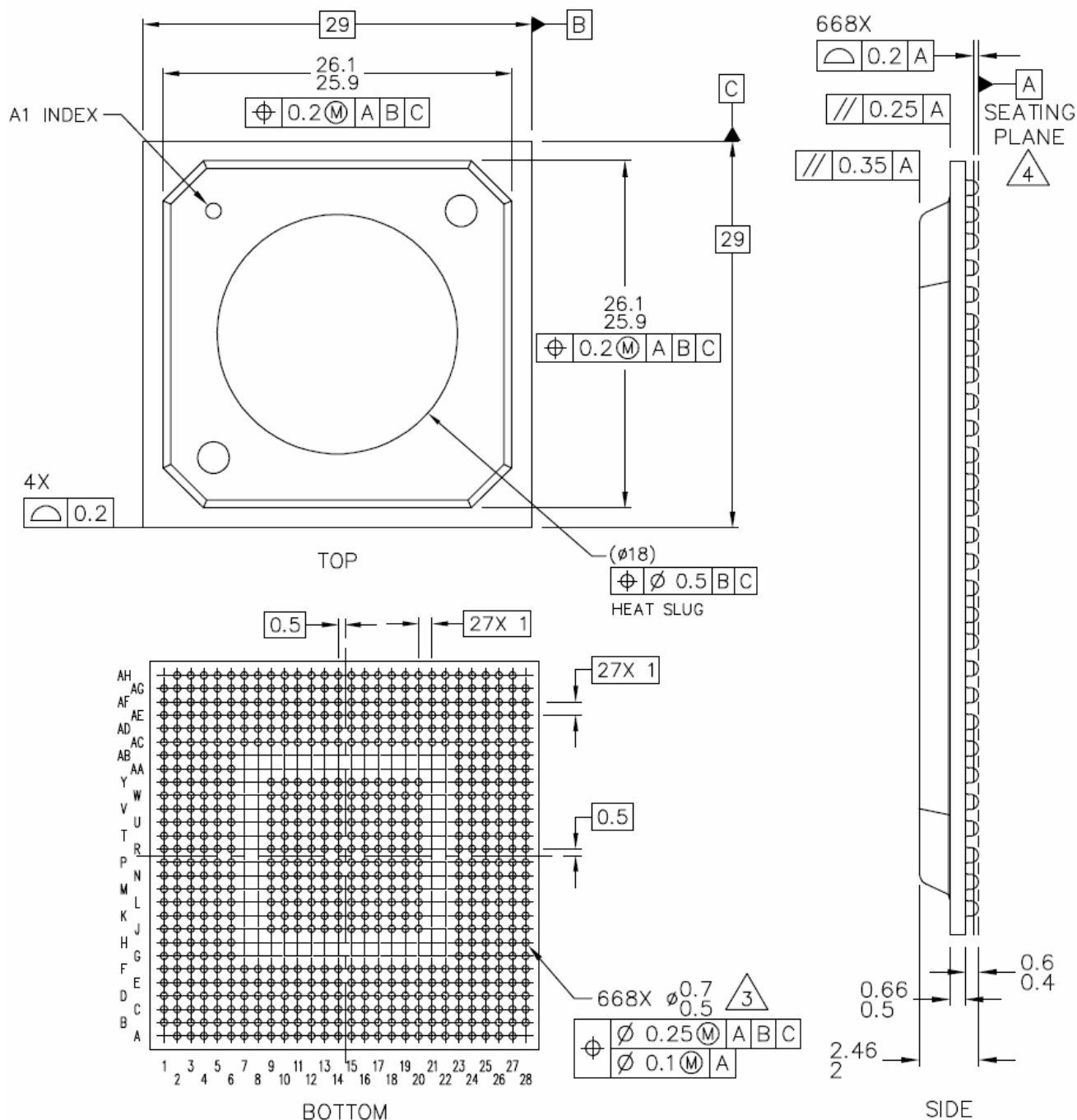


Figure 52. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package

### Notes:

1. All dimensions are in millimeters.
2. Dimensions and tolerances per ASME Y14.5M-1994.
3. Maximum solder ball diameter measured parallel to datum A.

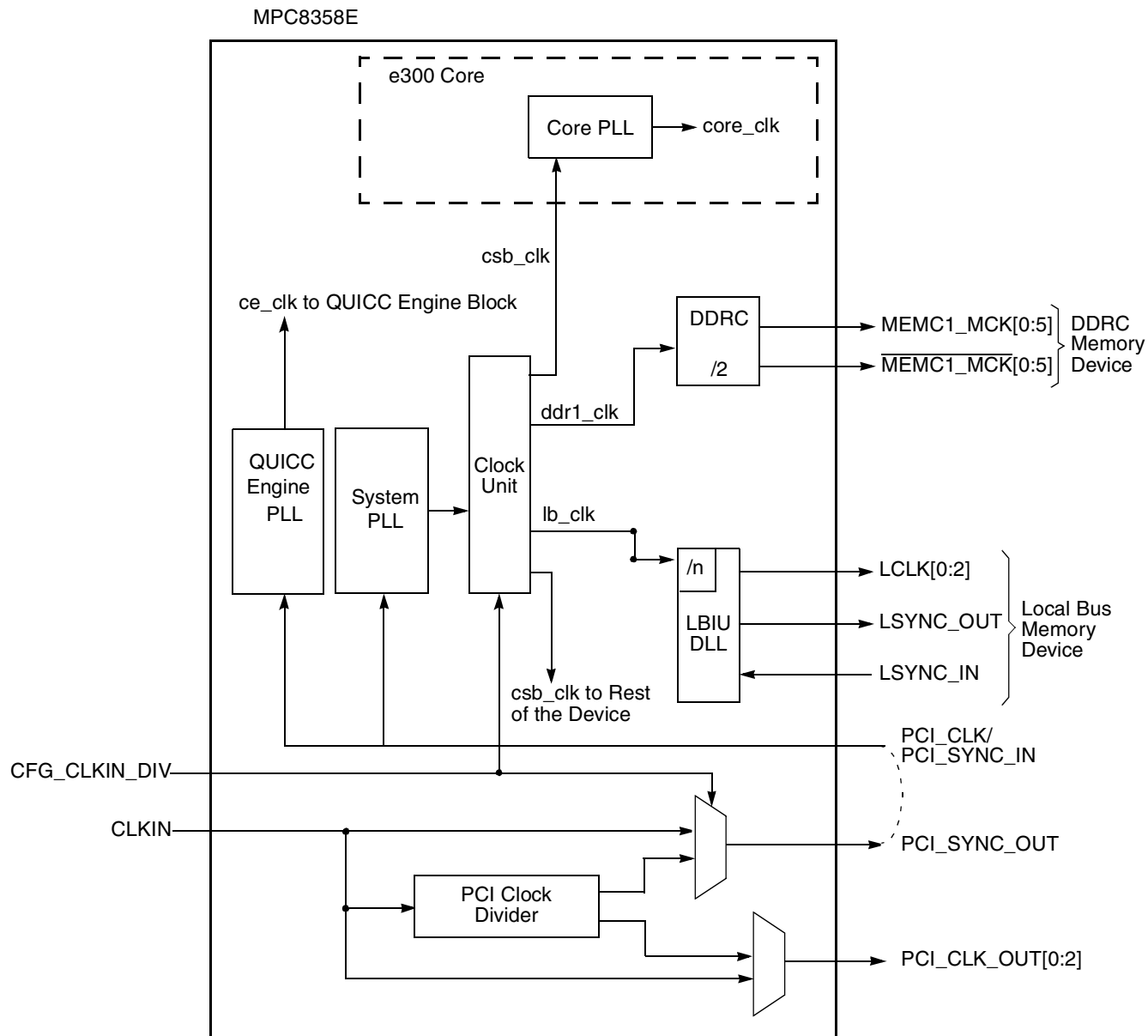
Table 65. MPC8358E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
TDI	AE8	I	OV <sub>DD</sub>	4
TDO	AG7	O	OV <sub>DD</sub>	3
TMS	AH7	I	OV <sub>DD</sub>	4
$\overline{\text{TRST}}$	AG8	I	OV <sub>DD</sub>	4
<b>Test</b>				
TEST	AF9	I	OV <sub>DD</sub>	7
$\overline{\text{TEST\_SEL}}$	AE27	I	GV <sub>DD</sub>	9
<b>PMC</b>				
$\overline{\text{QUIESCE}}$	AF4	O	OV <sub>DD</sub>	—
<b>System Control</b>				
$\overline{\text{PORESET}}$	AE9	I	OV <sub>DD</sub>	—
$\overline{\text{HRESET}}$	AG9	I/O	OV <sub>DD</sub>	1
$\overline{\text{SRESET}}$	AH10	I/O	OV <sub>DD</sub>	2
<b>Thermal Management</b>				
THERM0	K25	I	GV <sub>DD</sub>	—
THERM1	AA26	I	GV <sub>DD</sub>	—
<b>Power and Ground Signals</b>				
AV <sub>DD1</sub>	AF8	Power for LBIU DLL (1.2 V)	AV <sub>DD1</sub>	—
AV <sub>DD2</sub>	AH8	Power for CE PLL (1.2 V)	AV <sub>DD2</sub>	—
AV <sub>DD5</sub>	AB26	Power for e300 PLL (1.2 V)	AV <sub>DD5</sub>	—
AV <sub>DD6</sub>	AH9	Power for system PLL (1.2 V)	AV <sub>DD6</sub>	—
GND	C16, D11, D21, E24, F7, J10, J12, J15, J16, J17, J28, K11, K13, K14, K17, K18, L4, L9, L11, L12, L13, L14, L15, L16, L17, L18, L19, L24, M10, M11, M14, M15, M18, M19, N11, N18, N25, P9, P11, P18, P19, R9, R11, R14, R15, R18, R19, R26, T10, T11, T14, T15, T18, T25, U10, U11, U18, V9, V11, V14, V15, V18, V24, V27, W18, W19, Y11, Y14, Y18, Y19, Y25, Y27, AB4, AB27, AC27, AE20, AE24, AF5, AF15, AG10	—	—	—



## 22 Clocking

Figure 53 shows the internal distribution of clocks within the MPC8358E.



**Figure 53. MPC8358E Clock Subsystem**

The primary clock source for the device can be one of two inputs, CLKIN or PCI\_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Note that in PCI host mode, the primary clock input also depends on whether PCI clock outputs are selected with RCWH[PCICKDRV]. When the device is configured as a PCI host device (RCWH[PCIHOST] = 1) and PCI clock output is selected (RCWH[PCICKDRV] = 1), CLKIN is its primary input clock. CLKIN feeds the PCI clock divider ( $\div 2$ ) and the multiplexors for PCI\_SYNC\_OUT and PCI\_CLK\_OUT. The CFG\_CLKIN\_DIV configuration

input selects whether CLKIN or CLKIN/2 is driven out on the PCI\_SYNC\_OUT signal. The OCCR[PCIOEN<sub>n</sub>] parameters enable the PCI\_CLK\_OUT<sub>n</sub>, respectively.

PCI\_SYNC\_OUT is connected externally to PCI\_SYNC\_IN to allow the internal clock subsystem to synchronize to the system PCI clocks. PCI\_SYNC\_OUT must be connected properly to PCI\_SYNC\_IN, with equal delay to all PCI agent devices in the system, to allow the device to function. When the device is configured as a PCI agent device, PCI\_CLK is the primary input clock. When the device is configured as a PCI host device the CLKIN and the CFG\_CLKIN\_DIV signals should be tied to GND.

When the device is configured as a PCI host device (RCWH[PCIHOST] = 1) and PCI clock output is disabled (RCWH[PCICKDRV] = 0), clock distribution and balancing done externally on the board. Therefore, PCI\_SYNC\_IN is the primary input clock.

As shown in [Figure 53](#), the primary clock input (frequency) is multiplied by the QUICC Engine block phase-locked loop (PLL), the system PLL, and the clock unit to create the QUICC Engine clock (*ce\_clk*), the coherent system bus clock (*csb\_clk*), the internal DDRC1 controller clock (*ddr1\_clk*), and the internal clock for the local bus interface unit and DDR2 memory controller (*lb\_clk*).

The *csb\_clk* frequency is derived from a complex set of factors that can be simplified into the following equation:

$$csb\_clk = \{PCI\_SYNC\_IN \times (1 + CFG\_CLKIN\_DIV)\} \times SPMF$$

In PCI host mode,  $PCI\_SYNC\_IN \times (1 + CFG\_CLKIN\_DIV)$  is the CLKIN frequency; in PCI agent mode, CFG\_CLKIN\_DIV must be pulled down (low), so  $PCI\_SYNC\_IN \times (1 + CFG\_CLKIN\_DIV)$  is the PCI\_CLK frequency.

The *csb\_clk* serves as the clock input to the e300 core. A second PLL inside the e300 core multiplies up the *csb\_clk* frequency to create the internal clock for the e300 core (*core\_clk*). The system and core PLL multipliers are selected by the SPMF and COREPLL fields in the reset configuration word low (RCWL) which is loaded at power-on reset or by one of the hard-coded reset options. See Chapter 4, “Reset, Clocking, and Initialization,” in the *MPC8360E PowerQUICC II Pro Integrated Communications Processor Family Reference Manual* for more information on the clock subsystem.

The *ce\_clk* frequency is determined by the QUICC Engine PLL multiplication factor (RCWL[CEPMF]) and the QUICC Engine PLL division factor (RCWL[CEPDF]) according to the following equation:

$$ce\_clk = (\text{primary clock input} \times CEPMF) \div (1 + CEPDF)$$

The internal *ddr1\_clk* frequency is determined by the following equation:

$$ddr1\_clk = csb\_clk \times (1 + RCWL[DDR1CM])$$

Note that the *lb\_clk* clock frequency (for DDRC2) is determined by RCWL[LBCM]. The *internal ddr1\_clk* frequency is not the external memory bus frequency; *ddr1\_clk* passes through the DDRC1 clock divider ( $\div 2$ ) to create the differential DDRC1 memory bus clock outputs (MEMC1\_MCK and  $\overline{MEMC1\_MCK}$ ). However, the data rate is the same frequency as *ddr1\_clk*.

The internal *lb\_clk* frequency is determined by the following equation:

$$lb\_clk = csb\_clk \times (1 + RCWL[LBCM])$$

Note that *lb\_clk* is not the external local bus or DDRC2 frequency; *lb\_clk* passes through the a LB clock divider to create the external local bus clock outputs (LSYNC\_OUT and LCLK[0:2]). The LB clock divider ratio is controlled by LCRR[CLKDIV].

In addition, some of the internal units may be required to be shut off or operate at lower frequency than the *csb\_clk* frequency. Those units have a default clock ratio that can be configured by a memory mapped register after the device comes out of reset. Table 66 specifies which units have a configurable clock frequency.

**Table 66. Configurable Clock Units**

Unit	Default Frequency	Options
Security core	<i>csb_clk</i> /3	Off, <i>csb_clk</i> <sup>1</sup> , <i>csb_clk</i> /2, <i>csb_clk</i> /3
PCI and DMA complex	<i>csb_clk</i>	Off, <i>csb_clk</i>

<sup>1</sup> With limitation, only for slow *csb\_clk* rates, up to 166 MHz.

Table 67 provides the operating frequencies for the PBGA package under recommended operating conditions (see Table 2). All frequency combinations shown in the table below may not be available. Maximum operating frequencies depend on the part ordered, see Section 25.1, “Part Numbers Fully Addressed by this Document,” for part ordering details and contact your Freescale sales representative or authorized distributor for more information.

**Table 67. Operating Frequencies for the PBGA Package**

Characteristic <sup>1</sup>	400 MHz	Unit
e300 core frequency ( <i>core_clk</i> )	266–400	MHz
Coherent system bus frequency ( <i>csb_clk</i> )	133–266	MHz
QUICC Engine frequency ( <i>ce_clk</i> )	266–400	MHz
DDR and DDR2 memory bus frequency (MCLK) <sup>2</sup>	100–133	MHz
Local bus frequency (LCLK <sub>n</sub> ) <sup>3</sup>	16.67–133	MHz
PCI input frequency (CLKIN or PCI_CLK)	25–66.67	MHz
Security core maximum internal operating frequency	133	MHz

<sup>1</sup> The CLKIN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen such that the resulting *csb\_clk*, MCLK, LCLK[0:2], and *core\_clk* frequencies do not exceed their respective maximum or minimum operating frequencies.

<sup>2</sup> The DDR data rate is 2x the DDR memory bus frequency.

<sup>3</sup> The local bus frequency is 1/2, 1/4, or 1/8 of the *lb\_clk* frequency (depending on LCRR[CLKDIV]) which is in turn 1x or 2x the *csb\_clk* frequency (depending on RCWL[LBCM]).

## 22.4 Suggested PLL Configurations

To simplify the PLL configurations, the device might be separated into two clock domains. The first domain contains the CSB PLL and the core PLL. The core PLL is connected serially to the CSB PLL, and has the `csb_clk` as its input clock. The second clock domain has the QUICC Engine block PLL. The clock domains are independent, and each of their PLLs are configured separately. Both of the domains has one common input clock. Table 74 shows suggested PLL configurations for 33 and 66 MHz input clocks and illustrates each of the clock domains separately. Any combination of clock domains setting with same input clock are valid. Refer to Section 22, “Clocking,” for the appropriate operating frequencies for your device.

**Table 74. Suggested PLL Configurations**

Conf No. <sup>1</sup>	SPMF	CORE PLL	CEPMF	CEPDF	Input Clock Freq (MHz)	CSB Freq (MHz)	Core Freq (MHz)	QUICC Engine Freq (MHz)	400 (MHz)	533 (MHz)	667 (MHz)
<b>33 MHz CLKIN/PCI_SYNC_IN Options</b>											
s1	0100	0000100	æ	æ	33	133	266	—	∞	∞	∞
s2	0100	0000101	æ	æ	33	133	333	—	∞	∞	∞
s3	0101	0000100	æ	æ	33	166	333	—	∞	∞	∞
s4	0101	0000101	æ	æ	33	166	416	—	—	∞	∞
s5	0110	0000100	æ	æ	33	200	400	—	∞	∞	∞
s6	0110	0000110	æ	æ	33	200	600	—	—	—	∞
s7	0111	0000011	æ	æ	33	233	350	—	∞	∞	∞
s8	0111	0000100	æ	æ	33	233	466	—	—	∞	∞
s9	0111	0000101	æ	æ	33	233	583	—	—	—	∞
s10	1000	0000011	æ	æ	33	266	400	—	∞	∞	∞
s11	1000	0000100	æ	æ	33	266	533	—	—	∞	∞
s12	1000	0000101	æ	æ	33	266	667	—	—	—	∞
s13	1001	0000010	æ	æ	33	300	300	—	∞	∞	∞
s14	1001	0000011	æ	æ	33	300	450	—	—	∞	∞
s15	1001	0000100	æ	æ	33	300	600	—	—	—	∞
s16	1010	0000010	æ	æ	33	333	333	—	∞	∞	∞
s17	1010	0000011	æ	æ	33	333	500	—	—	∞	∞
s18	1010	0000100	æ	æ	33	333	667	—	—	—	∞
c1	æ	æ	01001	0	33	—	—	300	∞	∞	∞
c2	æ	æ	01100	0	33	—	—	400	∞	∞	∞
c3	æ	æ	01110	0	33	—	—	466	—	∞	∞
c4	æ	æ	01111	0	33	—	—	500	—	∞	∞

## How to Reach Us:

### Home Page:

[www.freescale.com](http://www.freescale.com)

### Web Support:

<http://www.freescale.com/support>

### USA/Europe or Locations Not Listed:

Freescale Semiconductor, Inc.  
Technical Information Center, EL516  
2100 East Elliot Road  
Tempe, Arizona 85284  
1-800-521-6274 or  
+1-480-768-2130  
[www.freescale.com/support](http://www.freescale.com/support)

### Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH  
Technical Information Center  
Schatzbogen 7  
81829 Muenchen, Germany  
+44 1296 380 456 (English)  
+46 8 52200080 (English)  
+49 89 92103 559 (German)  
+33 1 69 35 48 48 (French)  
[www.freescale.com/support](http://www.freescale.com/support)

### Japan:

Freescale Semiconductor Japan Ltd.  
Headquarters  
ARCO Tower 15F  
1-8-1, Shimo-Meguro, Meguro-ku  
Tokyo 153-0064  
Japan  
0120 191014 or  
+81 3 5437 9125  
[support.japan@freescale.com](mailto:support.japan@freescale.com)

### Asia/Pacific:

Freescale Semiconductor China Ltd.  
Exchange Building 23F  
No. 118 Jianguo Road  
Chaoyang District  
Beijing 100022  
China  
+86 10 5879 8000  
[support.asia@freescale.com](mailto:support.asia@freescale.com)

### For Literature Requests Only:

Freescale Semiconductor  
Literature Distribution Center  
1-800 441-2447 or  
+1-303-675-2140  
Fax: +1-303-675-2150  
[LDCForFreescaleSemiconductor@hibbertgroup.com](mailto:LDCForFreescaleSemiconductor@hibbertgroup.com)

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale, the Freescale logo, and PowerQUICC are trademarks of Freescale Semiconductor, Inc. Reg. U.S. Pat. & Tm. Off. QUICC Engine is a trademark of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners. The Power Architecture and Power.org word marks and the Power and Power.org logos and related marks are trademarks and service marks licensed by Power.org.  
© 2011 Freescale Semiconductor, Inc.

